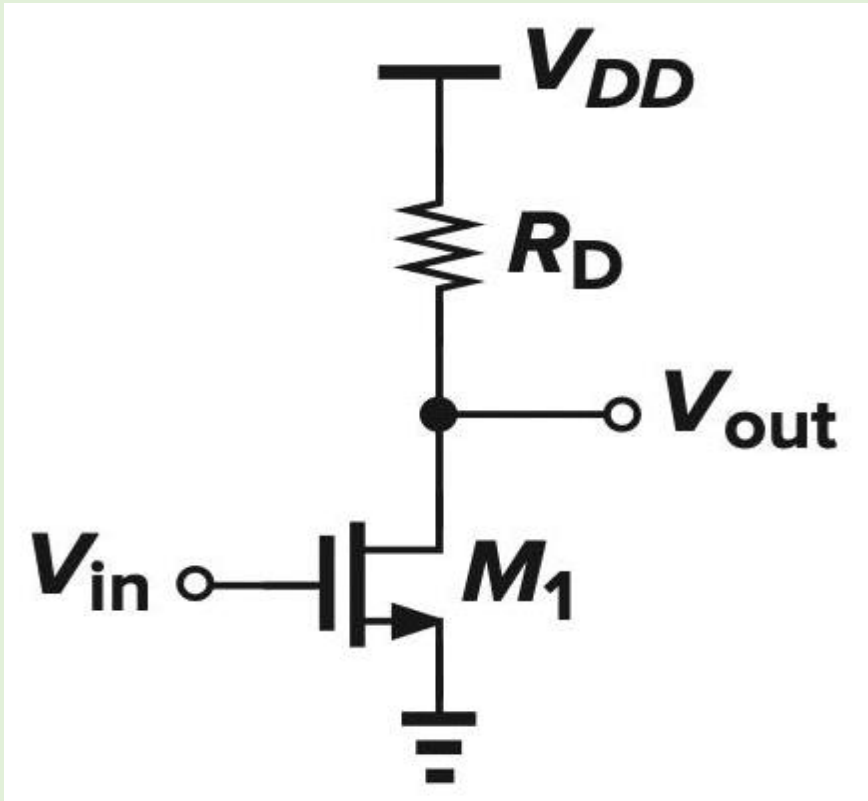


Prompt:

You are a professional analog circuit engineer. Please identify the type and function of this circuit diagram and reply in the following format:

Type:

Function:



GPT4V:

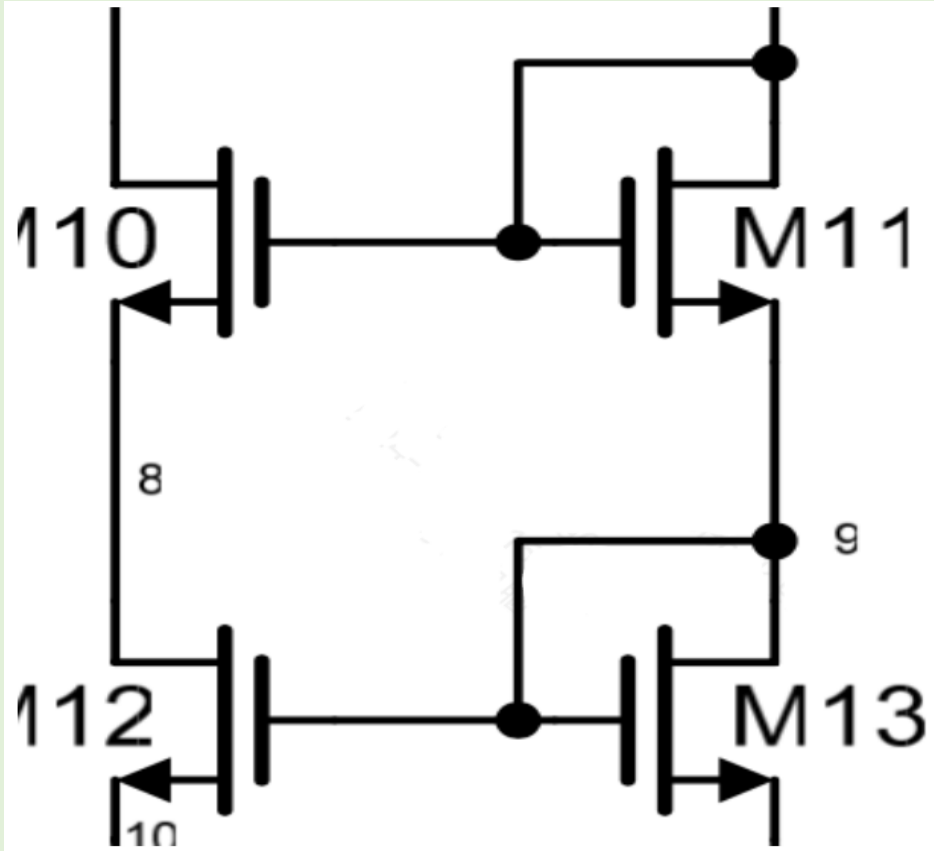
Type: Common Source Amplifier with NMOS Transistor

Function: This circuit is an electronic amplifier that uses an NMOS transistor as the active device. The input voltage signal ( $V_{in}$ ) is applied to the gate of the transistor ( $M_1$ ), and the output voltage ( $V_{out}$ ) is taken from the drain. The resistor ( $R_D$ ) serves as the load in the circuit. The common source amplifier configuration provides voltage amplification: the output voltage is an amplified inverted version of the input voltage. The transistor operates in the saturation region when used as an amplifier, acting as a controlled current source driven by the input voltage. This configuration is widely used in analog circuits, especially in applications where a high input impedance is beneficial and some gain is needed.

Prompt:

You are a professional analog circuit engineer. Please identify the type of this building block and reply in the following format:

Type:



GPT4V:

Type: Wilson Current Mirror

Building block library

class:Load

tag:Wilson Current Mirror

netlist:

M10 6 7 8 8 nch w=1u h=1u

M11 7 7 9 9 nch w=1u h=1u

M12 8 9 10 10 nch w=1u h=1u

M13 9 9 11 11 nch w=1u h=1u

Prompt(Some of the building blocks are shown here):

As a professional analog integrated circuit engineer, you are tasked with designing an operational amplifier that meets the following performance criteria:

DC Gain	Bandwidth	Gain Bandwidth Product (GBP)	Input Common-Mode (VCM) Range	Output Swing	Common-Mode Rejection Ratio (CMRR)	Power Supply Rejection Ratio (PSRR)	Slew Rate (SR)	Rise Time	Fall Time	Phase Margin	Power Consumption	Input-Referred Noise (IRN) Density
High	Wide	Moderate	Wide	Large	High	High	High	Short	Short	Sufficient	Low	Low

You can choose from the following building blocks to construct (the parameters of the components can be disregarded), please provide me with the correct selection:

### Differential pair

\*Differential pair (pmos)

M1 4 Vn 3 pch L=1u W=1u

M2 1 Vp 3 pch L=1u W=1u

\*Differential pair (nmos)

M1 1 Vin 2 nch L=1u W=1u

M2 3 Vip 2 nch L=1u W=1u

### Compensation

Bias Network

M3 4 Vin VSS nch L=1u W=1u

M4 5 Vip VSS nch L=1u W=1u

M5 Vop Vbn2 4 nch L=1u W=1u

### Load

Tail current

M5 3 Vb VDD pch L=1u W=1u

M7 2 Vb VDD pch L=1u W=1u

M6 2 1 VSS nch L=1u W=1u

Cascode

M7 Vop Vbp2 1 pch L=1u W=1u

M8 Von Vbp2 2 pch L=1u W=1u

M9 1 Vbp1 Vdd pch L=1u W=1u

M10 2 Vbp1 Vdd pch L=1u W=1u

Current mirror

M3 4 5 VSS nch L=1u W=1u

M4 1 5 VSS nch L=1u W=1u

Current source

M0 2 Vbn1 VSS nch

GPT4V:

From the building blocks you provide, we can assemble a more basic operational amplifier. In the process, we will combine different building blocks to realize the various functional parts of an operational amplifier, including differential inputs, current sources and loads, and frequency compensation. The following is a netlist description of an operational amplifier using the building blocks you provide.

\* Differential Input Stage

M1 in+ Vn pch L=1u W=1u ; PMOS input pair

M2 in- Vp pch L=1u W=1u ; PMOS input pair

\* Tail Current Source for Differential Pair

M3 S Vb VDD pch L=1u W=1u ; PMOS load for differential pair

M0 2 Vbn1 VSS nch ; NMOS tail current source

\* Active Load (Cascode Configuration)

M9 1 Vbp1 VDD pch L=1u W=1u ; PMOS cascode load

M10 2 Vbp1 VDD pch L=1u W=1u ; PMOS cascode load

M7 Vop Vbp2 1 pch L=1u W=1u ; PMOS cascode transistor

M8 Von Vbp2 2 pch L=1u W=1u ; PMOS cascode transistor

\* Current Mirror Load for Differential Pair

M3 4 5 VSS nch L=1u W=1u ; NMOS current mirror

M4 1 5 VSS nch L=1u W=1u ; NMOS current mirror

\* Bias Network

M6 Von Vbn2 5 nch L=1u W=1u ; NMOS bias for active load

M5 Vop Vbn2 4 nch L=1u W=1u ; NMOS bias for active load

M3 4 Vin VSS nch L=1u W=1u ; NMOS bias for differential pair

M4 5 Vip VSS nch L=1u W=1u ; NMOS bias for differential pair

\* Frequency Compensation

Rz 1 8 1k ; Compensation resistor

Cc 8 2 10pF ; Compensation capacitor

VDD VDD 0 5 ; Power supply

VSS VSS 0 -5 ; Ground

Vb Vb 0 2.5 ; Bias voltage for PMOS loads

Vbn1 Vbn1 0 -1.8 ; Bias voltage for NMOS tail source

Vbp1 Vbp1 0 3 ; Bias voltage for PMOS cascode load

Vbp2 Vbp2 0 2.5 ; Bias voltage for NMOS cascode transistor